

### Is Now Part of



## ON Semiconductor®

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (\_), the underscore (\_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (\_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at <a href="www.onsemi.com">www.onsemi.com</a>. Please email any questions regarding the system integration to Fairchild <a href="guestions@onsemi.com">guestions@onsemi.com</a>.

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### PN5134

### **NPN General Purpose Amplifier**

• This device is designed for use as general purpose amplifiers and switches requiring collector currents to 300mA.



1. Emitter 2. Base 3. Collector

### **Absolute Maximum Ratings\*** $T_A=25$ °C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CEO}$	Collector-Emitter Voltage	10	V
$V_{CBO}$	Collector-Base Voltage	20	V
V <sub>EBO</sub>	Emitter-Base Voltage	3.5	V
Ic	Collector Current - Continuous	500	mA
T <sub>J,</sub> T <sub>STG</sub>	Operating and Storage Junction Temperature Range	- 55 ~ 150	°C

<sup>\*</sup> These ratings are limiting values above which the serviceability of any semiconductor device may be impaird.

- These ratings are based on a maximum junction temperature of 150 degrees C.
   These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

### Electrical Characteristics T<sub>A</sub>=25°C unless otherwise noted

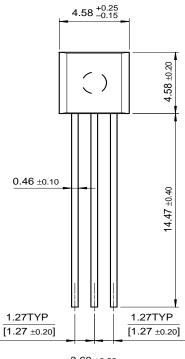
Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Charac	cteristics				
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage *	$I_C = 10 \text{mA}, I_B = 0$	10		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_C = 10\mu A, I_E = 0$	20		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 10\mu A, I_C = 0$	3.5		V
V <sub>(BR)CES</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10μA	20		V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 15V, I_{E} = 0, T_{A} = 65^{\circ}C$		10	μΑ
I <sub>CES</sub>	Collector Cutoff Current	V <sub>CB</sub> = 15V, I <sub>C</sub> = 0		0.4	μΑ
On Charac	cteristics	•	•		
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> = 1.0V, I <sub>C</sub> = 10mA	20	150	
		$V_{CE} = 0.4V, I_{C} = 30mA$	15		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = 10mA, I_B = 1.0mA$		0.25	V
		$I_C = 10mA, I_B = 3.3mA$		0.20	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	$I_C = 10mA, I_B = 1.0mA$	0.70	0.9	V
		$I_C = 10mA, I_B = 3.3mA$	0.72	1.1	V
Small Sign	nal Characteristics				
C <sub>ob</sub>	Output Capacitance	$V_{CB} = 5.0V, f = 1.0MHz$		4.0	pF
h <sub>fe</sub>	Small Signal Current Gain	I <sub>C</sub> = 10mA, V <sub>CE</sub> = 10V, f = 100MHz	2.5		
Switching	Characteristics	•	•		
t <sub>s</sub>	Storage Time	$I_C = I_{B1} = I_{B2} = 15\text{mA}$		18	ns
t <sub>on</sub>	Turn-on Time	$V_{CC} = 3.0V, I_{C} = 10mA$		18	ns
t <sub>d</sub>	Delay Time	I <sub>B1</sub> = 3.3mA		14	ns
t <sub>r</sub>	Rise Time			12	ns
t <sub>off</sub>	Turn-off Time	$V_{CC} = 3.0V, I_{C} = 10mA$		18	ns
t <sub>s</sub>	Storage Time	$I_{B1} = I_{B2} = 3.3 \text{mA}$		13	ns
t <sub>f</sub>	Fall Time			13	ns

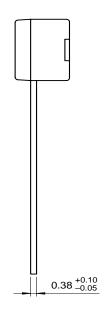
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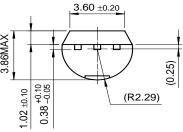
Thermal Characteristics T <sub>A</sub> =25°C unless otherwise noted			
Symbol	Parameter	Max.	Units
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	625 5.0	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

## **Package Dimensions**

TO-92







Dimensions in Millimeters

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E <sup>2</sup> CMOS <sup>TM</sup>	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I <sup>2</sup> C <sup>TM</sup>	OCXTM	RapidConfigure™	UHC™
Across the board.	Around the world.™	OCXPro™	RapidConnect™	UltraFET <sup>®</sup>
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### **Definition of Terms**

Datasheet Identification	Product Status	Definition
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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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